# NSR01F30MX

# **Schottky Barrier Diode**

These Schottky barrier diodes are optimized for low forward voltage drop and low leakage current.

## Features

- Very Low Forward Voltage Drop 350 mV @ 10 mA
- Low Reverse Current 5 µA @ 10 V
- 100 mA of Continuous Forward Current
- ESD Rating Human Body Model: Class 3B – Machine Model: Class C
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

## **Typical Applications**

- LCD and Keypad Backlighting
- Camera Photo Flash
- Buck and Boost dc-dc Converters
- Reverse Voltage and Current Protection
- Clamping & Protection

#### Markets

- Mobile Handsets
- MP3 Players
- Digital Camera and Camcorders
- Notebook PCs & PDAs
- GPS

# MAXIMUM RATINGS

Rating		Symbol	Value	Unit
Reverse Voltage		V <sub>R</sub>	30	V
Forward Current	Forward Current (DC)		100	mA
Forward Surge Current (60 Hz @ 1 cycle)		I <sub>FSM</sub>	2.0	A
ESD Rating:	Human Body Model Machine Model	ESD	>8.0 >400	kV V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



# **ON Semiconductor®**

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# 30 V SCHOTTKY BARRIER DIODE

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MARKING

X3DFN2 CASE 152AF



F = Specific Device Code

(Rotated 180°)

M = Date Code

# ORDERING INFORMATION

Device	Package	Shipping†
NSR01F30MXT5G	X3DFN2 (Pb–Free)	10000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# NSR01F30MX

### THERMAL CHARACTERISTICS

Characteristic		Min	Тур	Max	Unit
Thermal Resistance Junction-to-Ambient (Note 1) Total Power Dissipation @ $T_A = 25^{\circ}C$	R <sub>θJA</sub> P <sub>D</sub>			695 180	°C/W mW
Storage Temperature Range	T <sub>stg</sub>	-40		+125	°C
Junction Temperature Range	TJ	-40		+125	°C

1. Mounted onto a 4 in square FR-4 board 100 mm sq. 2 oz. Cu 0.06" thick single-sided. Operating to steady state.

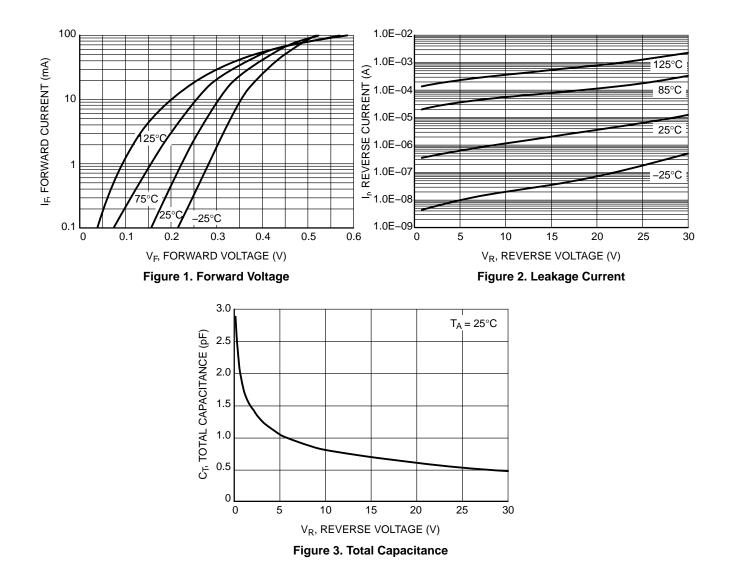
#### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Leakage $(V_R = 10 \text{ V})$ $(V_R = 30 \text{ V})$	I <sub>R</sub>			5 50	μΑ
Forward Voltage $(I_F = 10 \text{ mA})$ $(I_F = 100 \text{ mA})$	V <sub>F</sub>			0.35 0.60	V
Total Capacitance (V <sub>R</sub> = 10 V, f = 1 MHz)	СТ		0.90		pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

# NSR01F30MX

# **TYPICAL CHARACTERISTICS**



### MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

# onsemi

	<b>2x0.32x0.2</b> SE 152AF SSUE C	4, 0.35P			DAT	E 08 AUG	à 2023	
	AS	ME Y14 NTROL	INING ( 4.5M, 1 LING I	994.				
				MIL	LIMETER	S		
PIN 1			DIM	MIN.	NDM.	MAX.		
(ΠΡΤΙΠΝΔΙ.)			А	0.25	0.29	0.33		
TOP VIEW			A1	0.00		0.05	4	
<b>—</b> A1			A2	0.14	0.24	0.34	-	
// 0.05 C			b	0.22	0.25	0.28	-	
			b2	(	F	4		
			D	0.58	0.62	0.66	-	
			E	0.28	0.32	0.36	-	
SIDE VIEW C			e	(	0.355 BSC			
SIDE VIEW .			L2	0.17	0.20	0.23	4	
			L3	0.74—		F 2X 30		
		2Х	1	+[				
= 2x l2 ⊕0.05@[C A B] B□TT□M VIEW	* F	or addit	JNTING	ormation	PRINT;	Ph-Free	2	
GENERIC MARKING DIAGRAM*	s t T	trategy he ON S echnique	and sol emiconduc s Refere	dering di ctor Soli ence Mar	etails, p dering a nual, SOL	lease do nd Moun DERRM/D	wnload ting	
PIN 1 XM								

X = Specific Device Code M = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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 DESCRIPTION:
 X3DFN2 0.62x0.32x0.24, 0.35P
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